

# iscN-Channel MOSFET Transistor

## TK5A65DA, ITK5A65DA

## • FEATURES

• Low drain-source on-resistance:  $R_{DS}(ON) = 1.34\Omega$  (typ.)

Enhancement mode:
Vth = 2.4 to 4.4V (V<sub>DS</sub> = 10 V, I<sub>D</sub>=1.0mA)

- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

· Switching Voltage Regulators

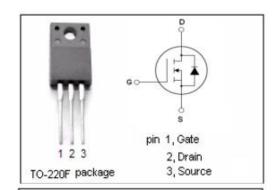


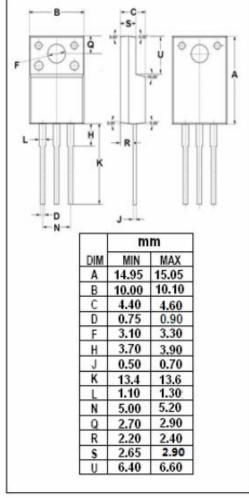
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
V <sub>GS</sub>	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-Continuous	4.5	А
I <sub>DM</sub>	Drain Current-Single Pulsed	18	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃		W
Tj	Max. Operating Junction Temperature 150		$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature -55~15		$^{\circ}$ C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.57	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance		°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	2.4		4.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =2.3A		1340	1670	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V			10	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =4.5A, V <sub>GS</sub> = 0 V			1.7	V

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